Semiconductors Devices

Lecturers: Prof. K. Thamilmaran

OBJECTIVES

This course deals with an introduction to semiconductor Devices.

SYLLABUS

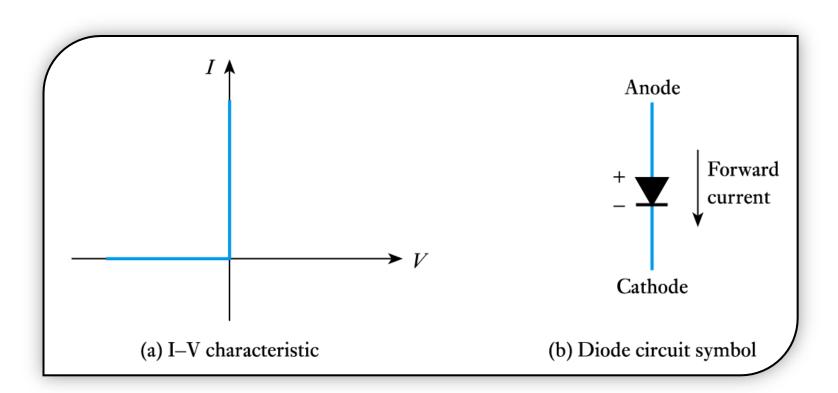
Semiconductors Devices: Metal - Semiconductor contacts (Ohmic and Schottky) - Schottky barrier diode - Zener diode - Varactor diode - Tunnel diode.

Semiconductor Diodes

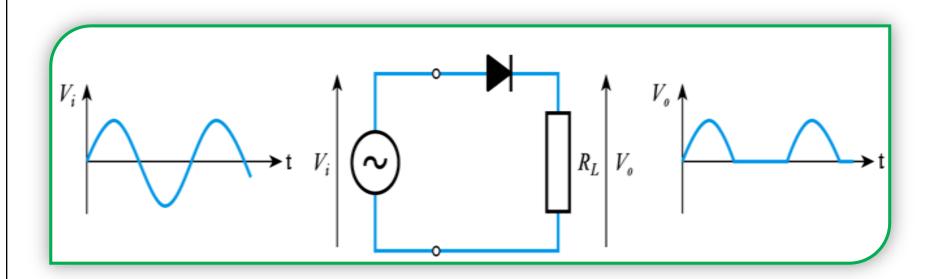
- Diodes
- Semiconductors
- pn Junctions
- Semiconductor Diodes
- **❖** Special-purpose Diodes

Diodes

An ideal diode passing electricity in one direction but not the other



- One application of diodes is in rectification
 The example below shows a half-wave rectifier
- In practice, no real diode has ideal characteristics but semiconductor pn junctions make good diodes
- To understand such devices we need to look at some properties of materials



Electrical Properties of Solids

Conductors

If an electric field is applied electrons will flow causing an electric current (at all temperatures above absolute zero).

e.g. copper or aluminium

Insulators

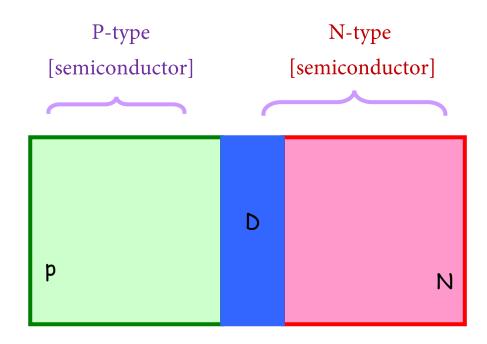
Electrons are tightly bound to atoms so few can break free to conduct electricity

e.g. Glass, Wood, polythene

Semiconductors

- Semiconductors have several properties that make them distinct from conductors and insulators
 - e.g. silicon ($V_B = 0.7$ volts) or germanium ($V_B = 0.3$ volts)
- At very low temperatures these have the properties of insulators
- The material warms up some electrons break free and can move about, and it takes on the properties of a conductor.

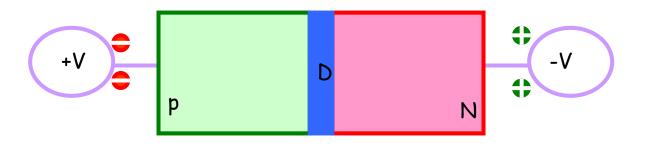
PN Junction



Depletion region, barrier to free flow of current from P to N \rightarrow insulator

PN Junction

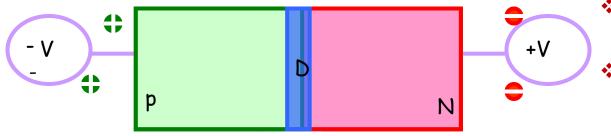
Forward Bias: Shrink depletion region, current dragged through the barrier



Once the difficulty of getting through the depletion region has been overcome, current can rise with applied voltage (Ohm's law)

Reverse Bias:

Grow depletion region, current finds it more and more difficult to get through the barrier

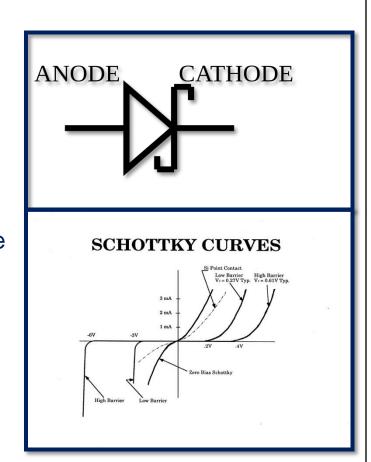


- Little current flows because barrier too high
- ♣ However increasing voltage further → high electric field
- ❖ Depletion region
 eventually breaks down
 → reverse current

Reverse

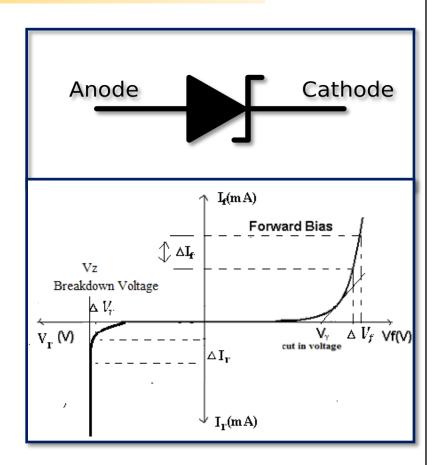
Schottky diode

- Junction between a layer of metal
 (e.g. aluminium) and a semiconductor
- Action relies only on majority charge carriers
- Much faster in operation than a pn junction diode
- A low forward voltage drop of about 0.25 V
- Used in the design of high-speed logic gates



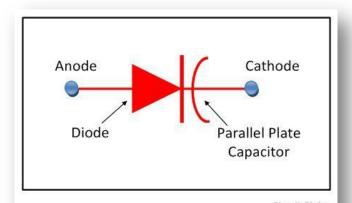
Zener diodes

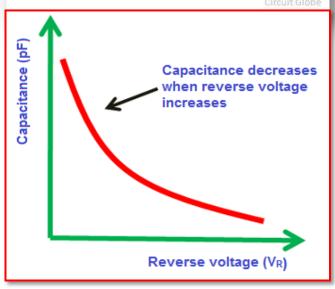
- The relatively constant reverse breakdown voltage to produce a voltage reference
- lacktriangledark Breakdown voltage is called the Zener voltage, V_{z}
- Output voltage of circuit shown is equal to V_Z despite variations in input voltage V
- A resistor is used to limit the current in the diode



Varactor diode (Varicap Diode)

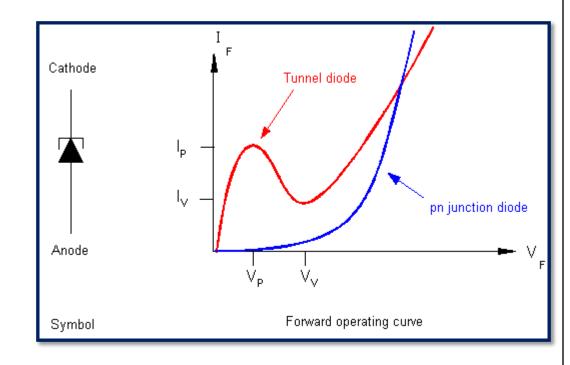
- A reversed-biased diode has two conducting
 regions separated by an insulating depletion region
- Variations in the reverse bias voltage change the width of the depletion layer and hence the capacitance
- This produces a voltage dependent capacitor
- These are used in applications such as
 automatic tuning circuits





Tunnel diodes

- High doping levels produce a very thin depletion layer which permits 'tunnelling' of charge carriers
- Results in a characteristic with a negative resistance region



 Used in high - frequency oscillators, where they can be used to 'cancel out' resistance in passive components

Key Points

- Diodes allow current to flow in only one direction
- At low temperatures semiconductors act like insulators
- At higher temperatures they begin to conduct
- ❖ Doping of semiconductors leads to the production of p-type and n-type materials
- ❖ A junction between p type and n type semiconductors has the properties of a diode
- Silicon semiconductor diodes approximate the behaviour of ideal diodes but have a conduction voltage of about 0.7 V and germanium 0.3 V
- There are also a wide range of special purpose diodes
- Diodes are used in a range of applications